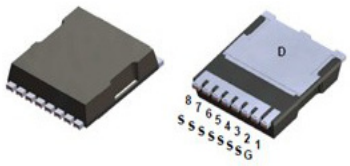
MOSFET – Power, Single N-Channel, TOLL

40 V, 240 A, 1.21 mΩ

FDBL9406-F085T6

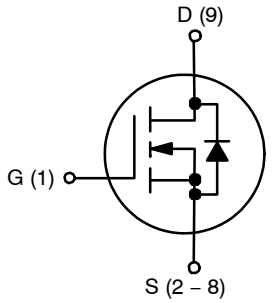
$V_{(BR)DSS}$	$R_{DS(ON)}$ MAX	I_D MAX
40 V	1.21 mΩ @ 10 V	240 A



H–PSOF8L
CASE 100CU

Features

- Low $R_{DS(on)}$ to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- Lowers Switching Noise/EMI
- AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Symbol	Parameter			Value	Unit
V_{DSS}	Drain–to–Source Voltage			40	V
V_{GS}	Gate–to–Source Voltage			+20/–16	V
I_D	Continuous Drain Current $R_{\theta JC}$ (Note 2)	Steady State	T_C = 25°C	240	A
			T_C = 100°C	179.4	
P_D	Power Dissipation $R_{\theta JC}$ (Note 2)		T_C = 25°C	136.4	W
			T_C = 100°C	68.2	
I_D	Continuous Drain Current $R_{\theta JA}$ (Notes 1, 2)	Steady State	T_A = 25°C	45	A
			T_A = 100°C	31.8	
P_D	Power Dissipation $R_{\theta JA}$ (Notes 1, 2)		T_A = 25°C	4.3	W
			T_A = 100°C	2.1	
I_{DM}	Pulsed Drain Current	T_A = 25°C, t_p = 10 μs		2817	A
T_J, T_{stg}	Operating Junction and Storage Temperature Range			–55 to +175	°C
I_S	Source Current (Body Diode)			221	A
E_{AS}	Single Pulse Drain–to–Source Avalanche Energy ($I_{L(pk)}$ = 42.5 A)			271	mJ
T_L	Lead Temperature Soldering Reflow for Soldering Purposes (1/8″ from case for 10 s)			260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Junction–to–Case – Steady State (Note 2)	1.1	°C/W
$R_{\theta JA}$	Junction–to–Ambient – Steady State (Note 2)	35	

1. Surface–mounted on FR4 board using a 1 in^2 pad size, 1 oz. Cu pad.
2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

ORDERING INFORMATION

Device	Package	Shipping†
FDBL9406–F085T6	H–PSOF8L (Pb–Free)	2,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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Table 1. ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
$V_{(BR)DSS}$	Drain−to−Source Breakdown Voltage	I_D = 250 μA, V_{GS} = 0 V	40			V
$V_{(BR)DSS}/T_J$	Drain−to−Source Breakdown Voltage Temperature Coefficient	I_D = 250 μA, V_{GS} = 0 V		24.9		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 40 V, V_{GS} = 0 V, T_J = 25°C			10	μA
I_{GSS}	Gate−to−Source Leakage Current	V_{DS} = 0 V, V_{GS} = +20/−16 V			±100	nA
ON CHARACTERISTICS (Note 3)						
$V_{GS(th)}$	Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = 190 μA	2	2.8	3.5	V
$V_{GS(th)}/T_J$	Negative Threshold Temperature Coefficient			−6.9		mV/°C
$R_{DS(on)}$	Drain−to−Source On Resistance	V_{GS} = 10 V, I_D = 50 A		1.1	1.21	mΩ
g_{FS}	Forward Transconductance	V_{DS} = 15 V, I_D = 50 A		143		S
CHARGES & CAPACTIANCES						
C_{iss}	Input Capacitance	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz		4960		pF
C_{oss}	Output Capacitance			2800		pF
C_{rss}	Reverse Transfer Capacitance			62		pF
$Q_{G(tot)}$	Total Gate Charge	V_{GS} = 10 V, V_{DS} = 20 V, I_D = 50 A		75		nC
$Q_{G(th)}$	Threshold Gate Charge			9		nC
Q_{gs}	Gate−to−Source Charge			22		nC
Q_{gd}	Gate−to−Drain Charge			16		nC
SWITCHING CHARACTERISTICS, V_{GS} = 10 V (Note 3)						
$t_{d(on)}$	Turn−On Delay Time	V_{GS} = 10 V, V_{DS} = 20 V, I_D = 50 A, R_G = 6 Ω		27		ns
t_r	Rise Time			44		ns
$t_{d(off)}$	Turn−Off Delay Time			61		ns
t_f	Fall Time			26		ns
DRAIN−SOURCE DIODE CHARACTERISTICS						
V_{SD}	Forward Diode Voltage	I_S = 50 A, V_{GS} = 0 V, T_J = 25°C		0.8	1.2	V
		I_S = 50 A, V_{GS} = 0 V, T_J = 125°C		0.6		V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, dI_S/d_t = 100 A/μs, I_S = 50 A		78		ns
t_a	Charge Time			39		ns
t_b	Discharge Time			39		ns
Q_{rr}	Reverse Recovery Charge			101		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Switching characteristics are independent of operating junction temperatures

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TYPICAL CHARACTERISTICS

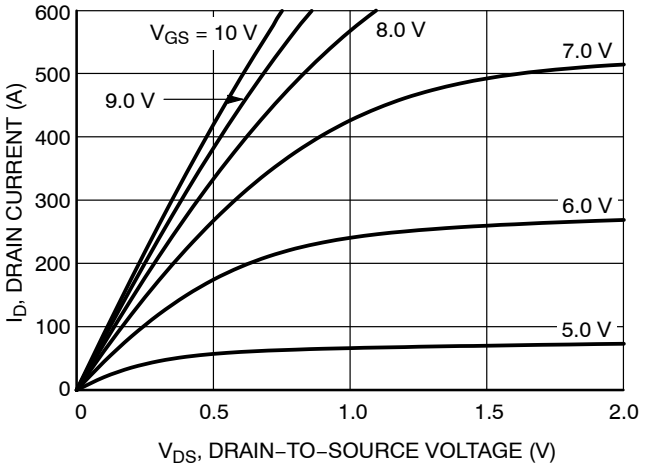


Figure 1. On−Region Characteristics

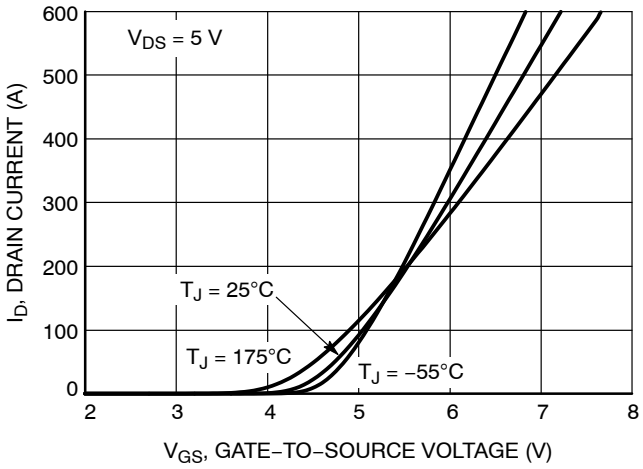


Figure 2. Transfer Characteristics

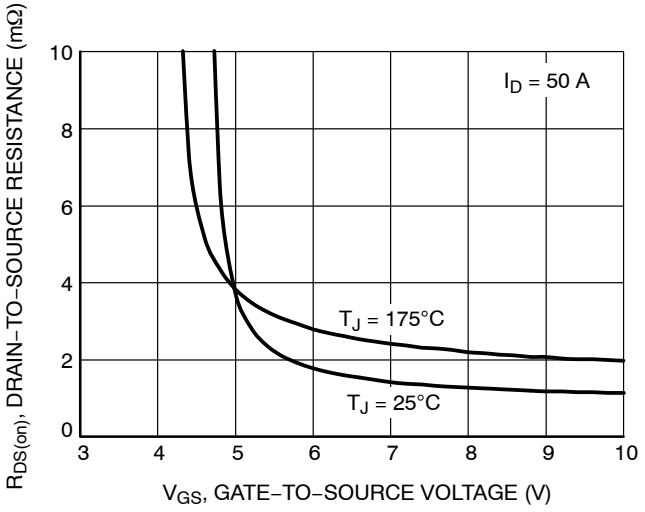


Figure 3. On−Resistance vs. Gate−to−Source Voltage

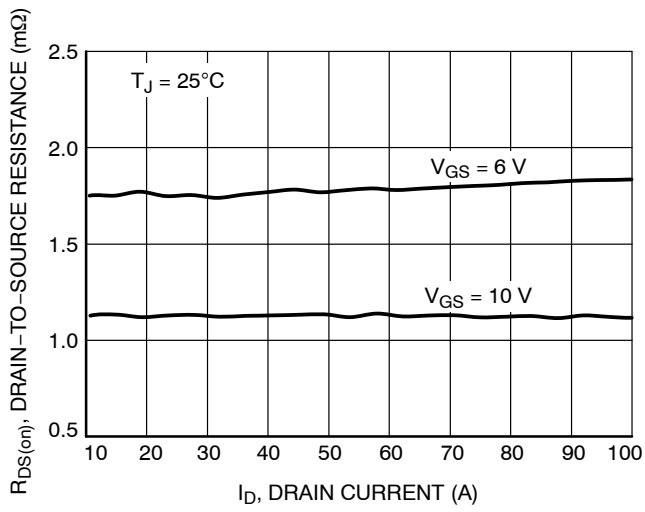


Figure 4. On−Resistance vs. Drain Current and Gate Voltage

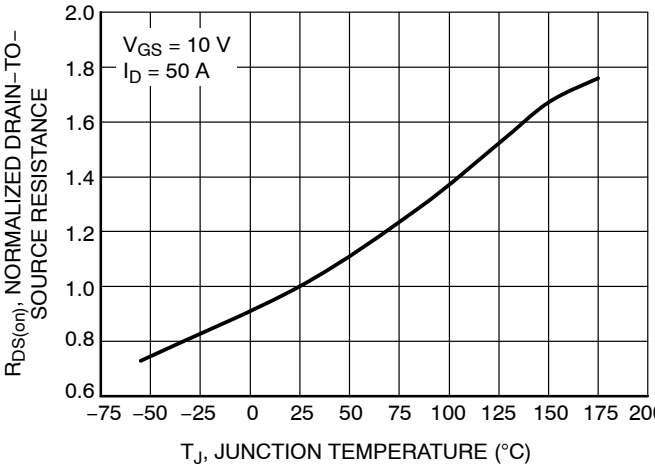


Figure 5. On−Resistance Variation with Temperature

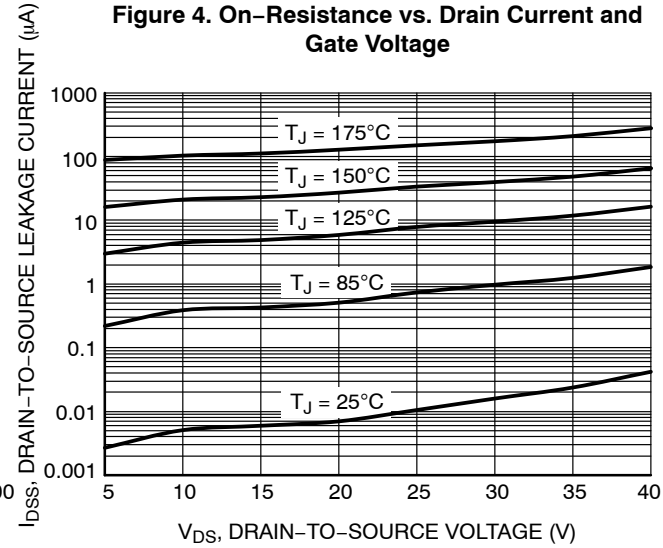


Figure 6. Drain−to−Source Leakage Current vs. Voltage

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TYPICAL CHARACTERISTICS (continued)

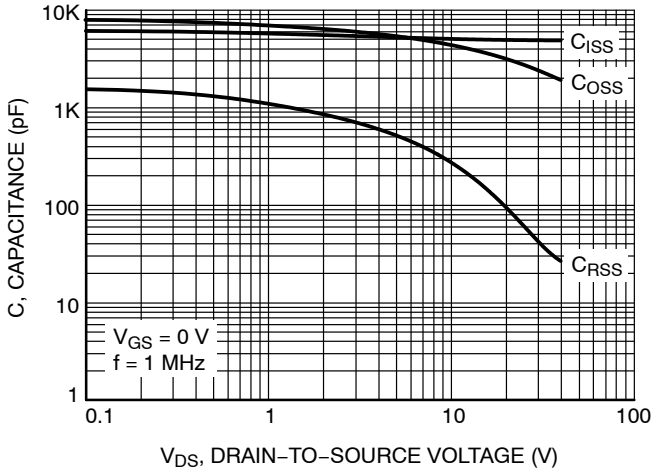


Figure 7. Capacitance Variation

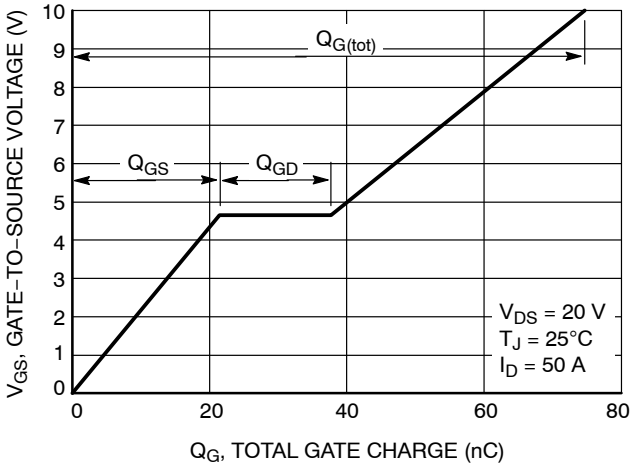


Figure 8. Gate−to−Source Voltage vs. Total Charge

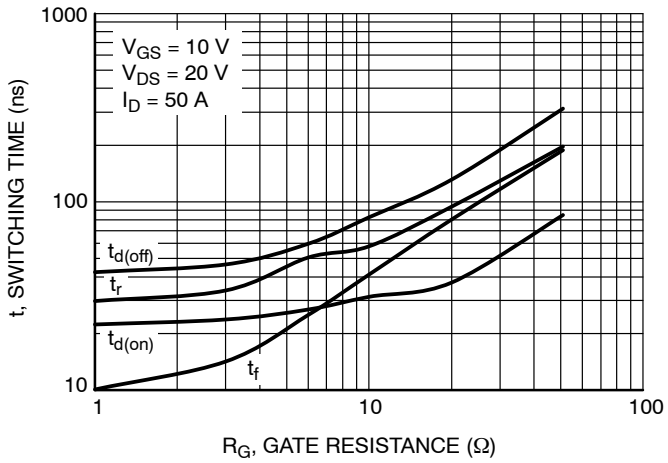


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

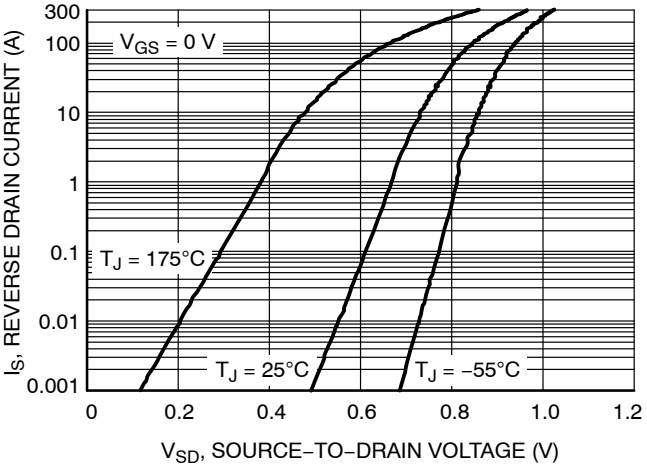


Figure 10. Diode Forward Voltage vs. Current

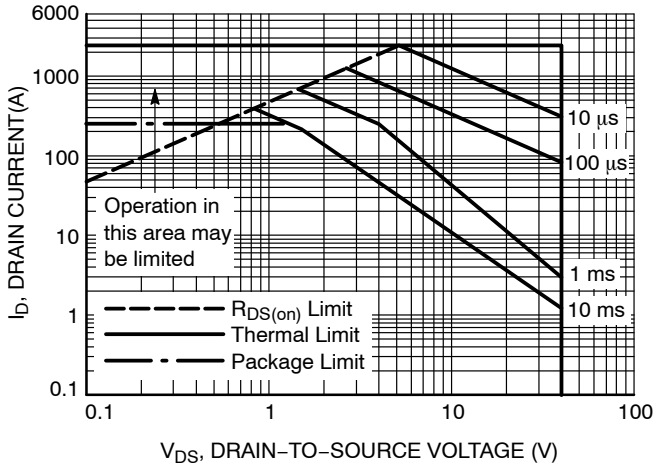


Figure 11. Maximum Rated Forward Biased Safe Operating Area

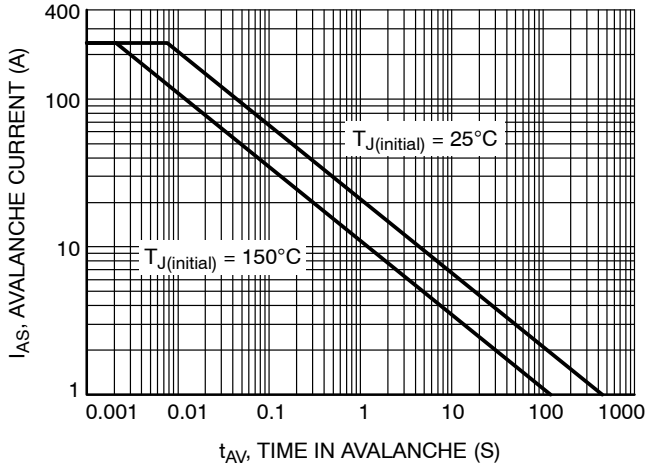


Figure 12. Maximum Drain Current vs. Time in Avalanche

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TYPICAL CHARACTERISTICS (continued)

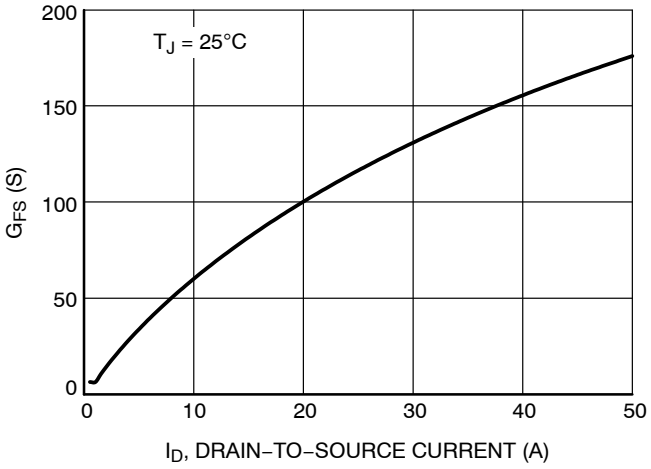


Figure 13. G_{FS} vs. I_D

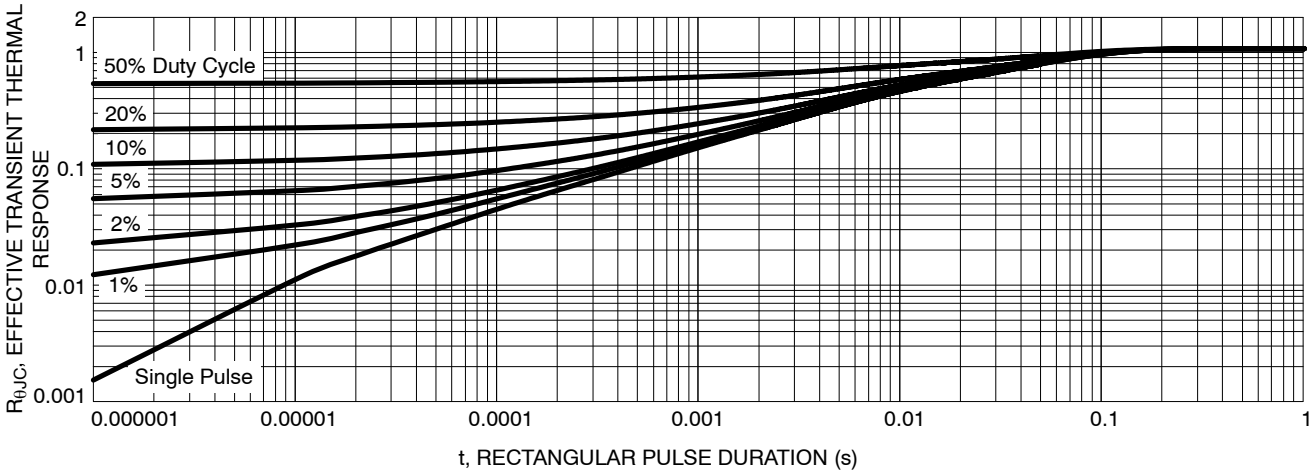
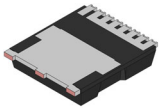


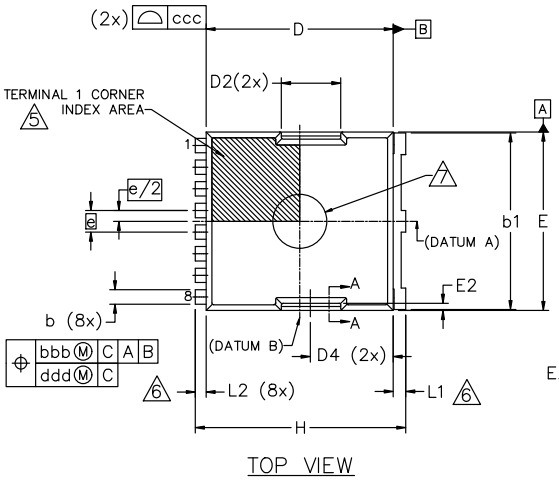
Figure 14. Thermal Response

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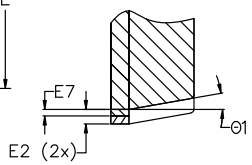


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CASE 100CU
ISSUE G

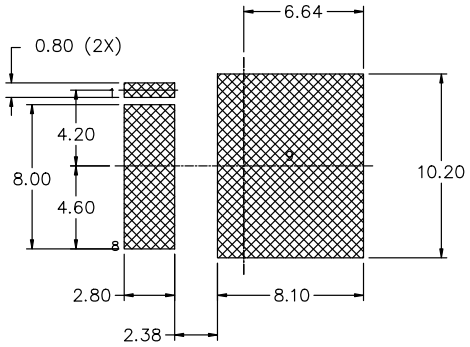
DATE 24 AUG 2026



TOP VIEW

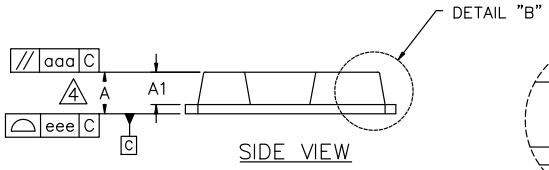


SECTION "A−A"
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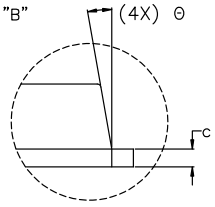


LAND PATTERN RECOMMENDATION

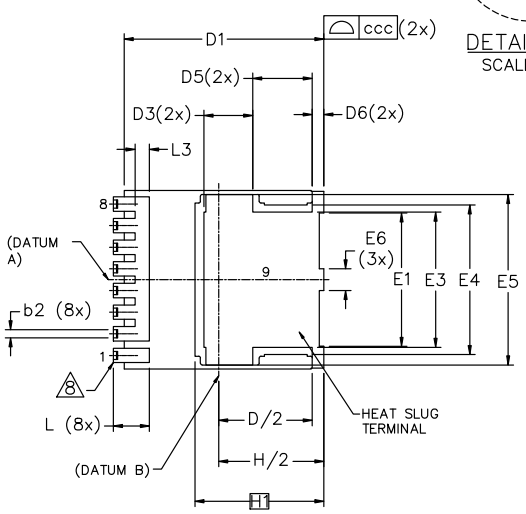
*FOR ADDITIONAL INFORMATION ON OUR PB−FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.



SIDE VIEW



DETAIL "B"
SCALE: 2X



BOTTOM VIEW

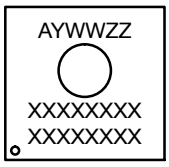
NOTES:
1. PACKAGE STANDARD REFERENCE: JEDEC MO−299, ISSUE B.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
3. "e" REPRESENTS THE TERMINAL PITCH.
4. COPLANARITY APPLIES TO EXPOSED PAD AND LEADS..
5. A VISUAL INDEX FEATURE MUST BE LOCATED WITHIN THE HATCHED AREA.
6. DIMENSIONS b1,L1,L2 APPLY TO PLATED TERMINALS.
7. THE LOCATION AND SIZE OF EJECTOR MARKS ARE OPTIONAL.
8. THE LOCATION AND NUMBER OF FUSED LEADS ARE OPTIONAL.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	2.20	2.30	2.40
A1	1.70	1.80	1.90
b	0.70	0.80	0.90
b1	9.70	9.80	9.90
b2	0.35	0.45	0.55
c	0.40	0.50	0.60
D	10.28	10.38	10.48
D/2	5.09	5.19	5.29
D1	10.98	11.08	11.18
D2	3.20	3.30	3.40
D3	2.60	2.70	2.80
D4	4.45	4.55	4.65
D5	3.20	3.30	3.40
D6	0.55	0.65	0.75
E	9.80	9.90	10.00
E1	7.30	7.40	7.50
E2	0.30	0.40	0.50
E3	7.40	7.50	7.60
E4	8.20	8.30	8.40

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
E5	9.36	9.46	9.56
E6	1.10	1.20	1.30
E7	0.15	0.18	0.21
e	1.20 BSC		
e/2	0.60 BSC		
H	11.58	11.68	11.78
H/2	5.74	5.84	5.94
H1	7.15 BSC		
L	1.90	2.00	2.10
L1	0.60	0.70	0.80
L2	0.50	0.60	0.70
L3	0.70	0.80	0.90
θ	10° REF		
θ1	10° REF		
aaa	0.20		
bbb	0.25		
ccc	0.20		
ddd	0.20		
eee	0.10		

GENERIC MARKING DIAGRAM*

A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code
XXXX = Specific Device Code



*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**H−PSOF8L 10.38x9.90x2.30, 1.20P**	**PAGE 1 OF 1**

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